ABSOLUTE MAXIMUM RATINGS

<i>,</i>		
V+ to V-, V-	+ to GND, GND to V	0.3V, +12V
Inputs		
Current:	IN_+, IN, HYST	20mA
Voltage:	IN_+, IN, HYST	(V+ + 0.3V) to $(V 0.3V)$
Outputs		
Current:	REF	20mA
	OUT	50mA
Voltage:	REF	$\dots (V + + 0.3V)$ to $(V 0.3V)$
	OUT_ (MAX9_1/9_4)	12V to (GND - 0.3V)
	(MAX9_2/9_3)	12V to (V 0.3V)
OUT_Sh	nort-Circuit Duration	Continuous
Continuous	Power Dissipation (TA =	+70°C)
8-Bump	UCSP (derate 4.7mW/°C	above +70°C)379mW

8-Pin Plastic DIP (derate 9.09mW/°C above +70°C)727mW 8-Pin SO (derate 5.88mW/°C above +70°C)471mW 8-Pin μMAX (derate 4.1mW/°C above +70°C)330mW 16-Pin Plastic DIP (derate 10.53mW/°C above +70°C)842mW
16-Pin SO (derate 8.70mW/°C above +70°C)696mW
Operating Temperature Ranges
MAX97_C/MAX98_C0°C to +70°C
MAX97_E/MAX98_E40°C to +85°C
Storage Temperature Range65°C to +150°C
Lead Temperature (soldering, 10s)+300°C
Bump Temperature (soldering)
Reflow+235°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—5V OPERATION

(V+ = 5V, V- = GND = 0V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 1)

PARAMETER	CONDITIONS				MIN	TYP	MAX	UNITS	
POWER REQUIREMENTS									
Supply Voltage Range	(Note 2)				2.5		11	V	
Output Voltage Range					0		11	V	
		MAX9_1,		T _A = +25°C		2.5	3.2		
		HYST = RE	EF	C/E temp ranges			4		
		MAX972		$T_A = +25^{\circ}C$		2.5	3.2		
	IN+ = IN- +	WIN ONOT Z		C/E temp ranges			4		
Supply Current	100mV	MAX982/ MAX9_3,		$T_A = +25^{\circ}C$		3.1	4.5	μΑ	
		HYST = RE	EF	C/E temp ranges			6		
		MAYO 4		$T_A = +25^{\circ}C$		5.5	6.5		
	MAX9_4 C/E temp ranges						8.5		
COMPARATOR	COMPARATOR								
Input Offset Voltage	$V_{CM} = 2.5V$						±10	mV	
Input Leakage Current (IN-, IN+)	IN+ = IN- = 2.	5V		C/E temp ranges		±0.01	±5	nA	
Input Leakage Current (HYST)	MAX9_1/MAX	982/MAX9_3				±0.02		nA	
Input Common-Mode Voltage Range					V-		V+ - 1.3	V	
Common-Mode Rejection Ratio	V- to (V+ - 1.3)	V)				0.1	1.0	mV/V	
Power-Supply Rejection Ratio	V+ = 2.5V to 1	1V				0.1	1.0	mV/V	
Voltage Noise	100Hz to 100kHz					20		μV _{RMS}	
Hysteresis Input Voltage Range	MAX9_1/MAX982/MAX9_3				REF - 0.05		REF	V	
Response Time (High-to-Low	T _A = +25°C, 100pF load, Overdrive = 10mV			12					
Transition)	$1M\Omega$ pullup to	$1M\Omega$ pullup to V+ Overdrive = 100 mV				4		μs	
Response Time (Low-to-High Transition) (Note 3)	$T_A = +25^{\circ}C, 1$	00pF load, 1N	МΩр	ullup to V+		300		μs	

ELECTRICAL CHARACTERISTICS—5V OPERATION (continued)

(V+ = 5V, V- = GND = 0V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 1)

PARAMETER	CO	NDITIONS	MIN	TYP	MAX	UNITS		
	MAX9_2/MAX9_3, I _O U	_{JT} = 1.8mA			V- + 0.4			
Output Low Voltage	MAX9_1/MAX9_4, IOL	JT = 1.8mA			GND + 0.4	V		
Output Leakage Current	V _{OUT} = 11V					100	nA	
REFERENCE (MAX9_1/MAX982/MAX9_3/MAX9_4 ONLY)								
	MAX971/MAX973/	C temp range	1%	1.170	1.182	1.194	V	
Poforonoo Voltago	MAX974	E temp range	2%	1.158		1.206		
Reference Voltage	MAX981-MAX984	C temp range	2%	1.158	1.182	1.206		
	IVIAN961-IVIAN964	E temp range	3%	1.147		1.217		
Source Current	$T_A = +25^{\circ}C$			15	25			
Source Current	C/E temp ranges		6			μΑ		
Sink Current	T _A = +25°C			8	15			
SIIIK GUITEIT	C/E temp ranges	·	4			μΑ		
Voltage Noise	100Hz to 100kHz				100		μV _{RMS}	

ELECTRICAL CHARACTERISTICS—3V OPERATION

(V+ = 3V, V- = GND = 0V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 1)

PARAMETER	CONDITIONS			MIN	TYP	MAX	UNITS
POWER REQUIREMENTS							
		MAYO 1	$T_A = +25^{\circ}C$		2.4	3.0	
		MAX9_1	C/E temp ranges		2.4 2.4 3.4 5.2 ±0.01 ±0.02	3.8	
		MAX972	$T_A = +25^{\circ}C$	2.4 2.4 3.4 5.2	3.0	μA	
Supply Current	HYST = REF, IN+ = (IN- +	IVIAA912	C/E temp ranges		3.8		
Supply Current	100mV)	MAX982/	$T_A = +25^{\circ}C$		3.4	4.3	μΑ
	, ,	MAX9_3	C/E temp ranges			5.8	
		MAX9_4	T _A = +25°C		5.2	6.2	
			C/E temp ranges			8.0	
COMPARATOR							
Input Offset Voltage	$V_{CM} = 1.5V$					±10	mV
Input Leakage Current (IN-, IN+)	IN+ = IN- = 1.	5V	C/E temp ranges		±0.01	±5	nA
Input Leakage Current (HYST)	MAX9_1/MAX9	982/MAX9_3			±0.02		nA
Input Common-Mode Voltage Range		V-		V+ - 1.3	V		
Common-Mode Rejection Ratio	V- to (V+ - 1.3)	V)			0.2	1	mV/V
Power-Supply Rejection Ratio	V+ = 2.5V to 1		0.1	1	mV/V		
Voltage Noise	100Hz to 100k		20		μV _{RMS}		
Hysteresis Input Voltage Range	MAX9_1/MAX9		REF - 0.05		REF	V	



ELECTRICAL CHARACTERISTICS—3V OPERATION (continued)

(V+ = 3V, V- = GND = 0V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 1)

PARAMETER	CON	CONDITIONS				TYP	MAX	UNITS	
Response Time (High-to-Low	$T_A = +25^{\circ}C$, 100pF lo	°C, 100pF load, Overdrive = 10mV			12				
Transition)	$1M\Omega$ pullup to V+	(Overdrive =	100mV		4		μs	
Response Time (Low-to-High Transition) (Note 3)	$T_A = +25^{\circ}C$, 100pF lo	$T_A = +25$ °C, 100pF load, 1M Ω pullup to V+				300		μs	
Output Low Voltage	MAX9_2/MAX9_3, I _O U	MAX9_2/MAX9_3, I _{OUT} = 0.8mA					V- + 0.4	V	
Output Low Voltage	MAX9_1/MAX9_4, I _O U	MAX9_1/MAX9_4, I _{OUT} = 0.8mA					GND + 0.4	V	
Output Leakage Current	V _{OUT} = 11V	V _{OUT} = 11V					100	nA	
REFERENCE									
	MAX971/MAX973/	C ter	mp range	1%	1.170	1.182	1.194		
	MAX974	E ter	np range	2%	1.158		1.206	V	
Reference Voltage	MAX981-MAX984	C ter	mp range	2%	1.158	1.182	1.206	V	
	IVIAA901-IVIAA904	E ter	np range	3%	1.147		1.217		
Source Current	$T_A = +25^{\circ}C$				15	25			
Source Current	C/E temp ranges	C/E temp ranges						μΑ	
Sink Current	T _A = +25°C	T _A = +25°C							
Sink Current	C/E temp ranges	C/E temp ranges 4						μA	
Voltage Noise	100Hz to 100kHz	. 5						μV _{RMS}	

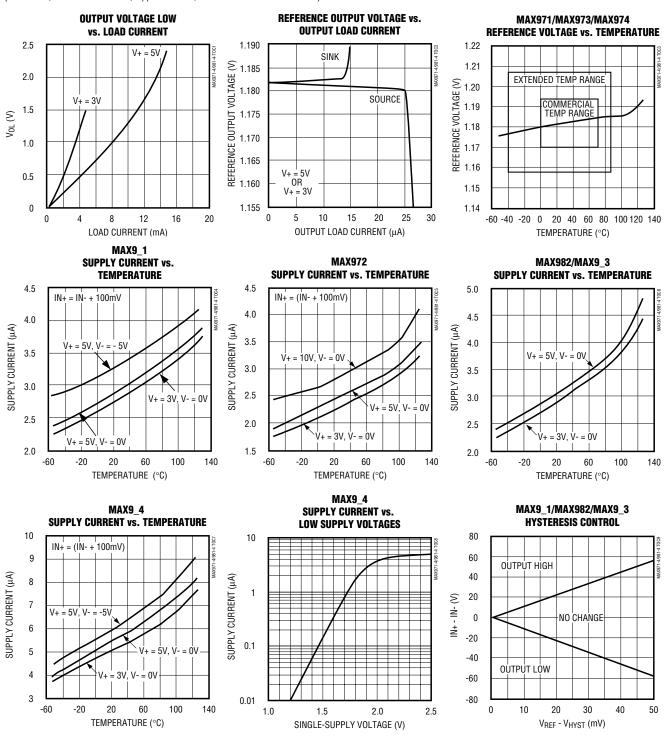
Note 1: The MAX972EBL is 100% tested at $T_A = +25$ °C. Temperature limits are guaranteed by design.

Note 2: MAX974/MAX984 comparators work below 2.5V; see Low-Voltage Operation section for more details.

Note 3: Low-to-high response time is the result of the $1M\Omega$ pullup and the 100pF capacitive load, based on three time constants. A faster response time is achieved with a smaller RC.

Typical Operating Characteristics

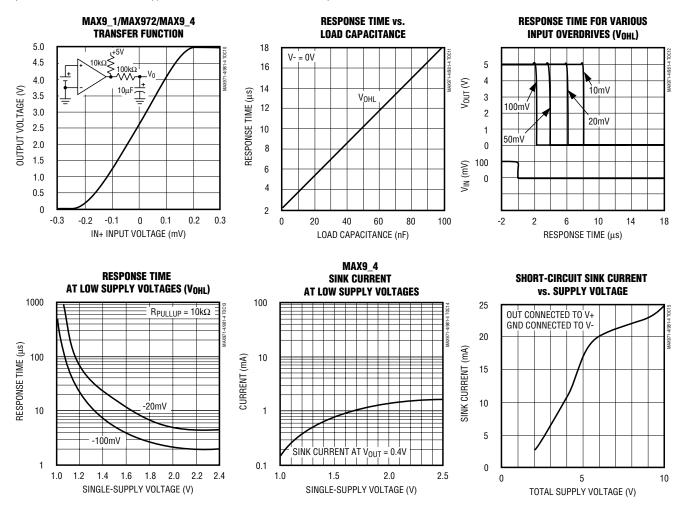
 $(V+ = 5V, V- = GND = 0V, T_A = +25^{\circ}C, unless otherwise noted.)$



NIXIN

Typical Operating Characteristics (continued)

 $(V+ = 5V, V- = GND = 0V, T_A = +25$ °C, unless otherwise noted.)



Pin Description

		PIN				
MAX971/ MAX981	МАХ	972	MAX982	MAX973/ MAX983	NAME	FUNCTION
DIP/SO/ µMAX	DIP/SO/ µMAX	UCSP	DIP/SO/ µMAX	DIP/SO/ µMAX		
1			_	_	GND	Ground. Connect to V- for single-supply operation.
2	2	C2	2	2	V-	Negative Supply. Connect to GND for single-supply operation (MAX9_1).
3	_	_	_	_	IN+	Noninverting Comparator Input
4	ĺ		_	_	IN-	Inverting Comparator Input
5	_	_	5	5	HYST	Hysteresis Input. Connect to REF if not used. Input voltage range is from V_{REF} to $(V_{REF} - 50 \text{mV})$.
6	_	_	6	6	REF	Reference Output. 1.182V with respect to V
7	7	A2	7	7	V+	Positive Supply
8	_	_	_	_	OUT	Comparator Output. Sinks current to GND.
	1	A1	1	1	OUTA	Comparator A Open-Drain Output. Sinks current to V
_	3	C1	3	3	INA+	Noninverting Input of Comparator A
	4	B1	_	_	INA-	Inverting Input of Comparator A
_	5	В3	_	4	INB-	Inverting Input of Comparator B
	6	C3	4	_	INB+	Noninverting Input of Comparator B
_	8	А3	8	8	OUTB	Comparator B Open-Drain Output. Sinks current to V



Pin Description (continued)

PIN						
MAX974 MAX984	NAME	FUNCTION				
1	OUTB	Comparator B Open-Drain Output. Sinks current to GND.				
2	OUTA	Comparator A Open-Drain Output. Sinks current to GND.				
3	V+	Positive Supply				
4	INA-	Inverting Input of Comparator A				
5	INA+	Noninverting Input of Comparator A				
6	INB-	Inverting Input of Comparator B				
7	INB+	Noninverting Input of Comparator B				
8	REF	Reference Output. 1.182V with respect to V				
9	V-	Negative Supply. Connect to ground for single-supply operation.				
10	INC-	Inverting Input of Comparator C				
11	INC+	Noninverting Input of Comparator C				
12	IND-	Inverting Input of Comparator D				
13	IND+	Noninverting Input of Comparator D				
14	GND	Ground. Connect to V- for single-supply operation.				
15	OUTD	Comparator D Open-Drain Output. Sinks current to GND.				
16	OUTC	Comparator C Open-Drain Output. Sinks current to GND.				

8 ______ **/\/\/**

Detailed Description

The MAX971–MAX974/MAX981–MAX984 comprise various combinations of a micropower 1.182V reference and micropower comparators. The *Typical Operating Circuit* shows the MAX971/MAX981 configuration, and Figures 1a–1d show the MAX9_2-MAX9_4 configurations.

Internal hysteresis in the MAX9_1, MAX982, and MAX9_3 provides the easiest method for implementing hysteresis. It also produces faster hysteresis action and consumes much less current than circuits using external positive feedback.

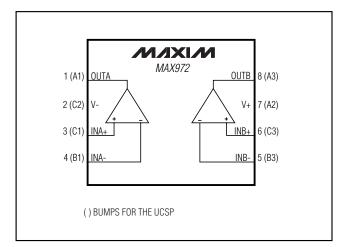


Figure 1a. MAX972 Functional Diagram

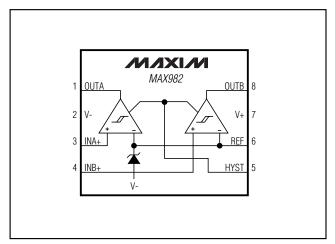


Figure 1b. MAX982 Functional Diagram

Power-Supply and Input Signal Ranges

This family of devices operates from a single 2.5V to 11V power supply. The MAX9_1 and MAX9_4 have a separate ground for the output driver, allowing operation with dual supplies ranging from ±1.25V to ±5.5V. Connect V- to GND when operating the MAX9_1 or MAX9_4 from a single supply. The maximum total supply voltage in this case is still 11V.

For proper comparator operation, the input signal can range from the negative supply (V-) to within one volt of the positive supply (V+ - 1V). The guaranteed common-mode input voltage range extends from V- to (V+ - 1.3V). The inputs can be taken above and below the supply rails by up to 300mV without damage.

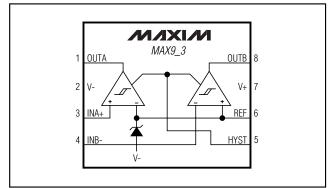


Figure 1c. MAX973/MAX983 Functional Diagram (Window Comparator)

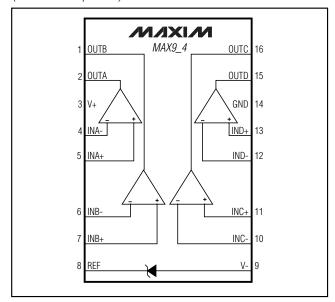


Figure 1d. MAX974/MAX984 Functional Diagram



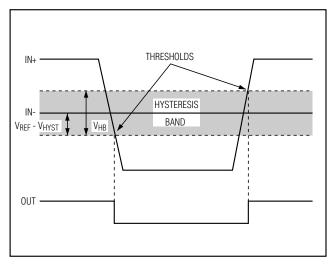


Figure 2. Threshold Hysteresis Band

Low-Voltage Operation: V+ = 1V (MAX9_4 Only)

The guaranteed minimum operating voltage is 2.5V (or ±1.25V). As the total supply voltage falls below 2.5V, performance degrades and the supply current falls. The reference will not function below about 2.2V, although the comparators will continue to operate with a total supply voltage as low as 1V. While the MAX9_4 has comparators that may be used at supply voltages below 2V, the MAX9_1/MAX9_2/MAX9_3 may not be used with supply voltages below 2.5V.

At low supply voltages, the comparators' output sink capability is reduced and the propagation delay increases (see *Typical Operating Characteristics*). The useful input voltage range extends from the negative supply to a little under 1V below the positive supply, which is slightly closer to the positive rail than when the device operates from higher supply voltages. Test your prototype over the full temperature and supply-voltage range if you anticipate operation below 2.5V.

Comparator Output

With 100mV of overdrive, propagation delay is typically $3\mu s$. The *Typical Operating Characteristics* show the propagation delay for various overdrive levels. The open-drain outputs are intended for wire-ORed and level-shifting applications. The maximum output voltage is 11V above V-, and may be applied even when no supply voltage is present (V+ = V-).

The MAX9_1 and MAX9_4 outputs sink current to GND, making these devices ideal for bipolar to single-ended conversion and level-shifting applications.

The negative supply does not affect the output sink current. The positive supply provides gate drive for the output N-channel MOSFET and heavily influences the output current capability, especially at low supply voltages (see *Typical Operating Characteristics* section).

The MAX9_2 and MAX9_3 have no GND pin, and their outputs sink current to V-.

Voltage Reference

The internal bandgap voltage reference has an output of 1.182V above V-. Note that the REF voltage is referenced to V-, not to GND. Its accuracy is $\pm 1\%$ (MAX971/MAX973/MAX974) or $\pm 2\%$ (MAX981–MAX984) in the 0°C to +70°C range. The REF output is typically capable of sourcing 25µA and sinking 15µA. Do not bypass the REF output.

Noise Considerations

Although the comparators have a very high gain, useful gain is limited by noise. This is shown in the Transfer Function graph (see *Typical Operating Characteristics*). As the input voltage approaches the comparator's offset, the output begins to bounce back and forth; this peaks when $V_{IN} = V_{OS}$. (The lowpass filter shown on the graph averages out the bouncing, making the transfer function easy to observe.) Consequently, the comparator has an effective wideband peak-to-peak noise of around 300µV. The voltage reference has peak-to-peak noise approaching 1mV. Thus, when a comparator is used with the reference, the combined peak-to-peak noise is about 1mV. This, of course, is much higher than the RMS noise of the individual components. Take care in your layout to avoid capacitive coupling from any output to the reference pin. Crosstalk can significantly increase the actual noise of the reference.

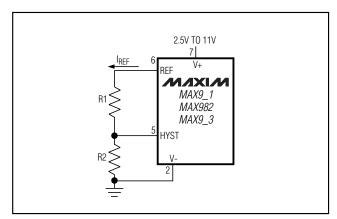


Figure 3. Programming the HYST Pin

Applications Information

Hysteresis

Hysteresis increases the comparators' noise margin by increasing the upper threshold and decreasing the lower threshold (Figure 2).

Hysteresis (MAX9_1/MAX982/MAX9_3)

To add hysteresis to the MAX9_1, MAX982, or MAX9_3, connect resistor R1 between REF and HYST, and connect resistor R2 between HYST and V- (Figure 3). If no hysteresis is required, connect HYST to REF. When hysteresis is added, the upper threshold increases by the same amount that the lower threshold decreases. The hysteresis band (the difference between the upper and lower thresholds, V_{HB}) is approximately equal to twice the voltage between REF and HYST. The HYST input can be adjusted to a maximum voltage of REF and to a minimum voltage of (REF - 50mV). The maximum difference between REF and HYST (50mV) will therefore produce a 100mV (max) hysteresis band. Use the following equations to determine R1 and R2:

$$R1 = \frac{V_{HB}}{(2 \times I_{REF})}$$

$$R2 = \frac{\left(1.182 - \frac{V_{HB}}{2}\right)}{I_{REF}}$$

where I_{REF} (the current sourced by the reference) should not exceed the REF source capability, and should be significantly larger than the HYST input current. I_{REF} values between 0.1µA and 4µA are usually appropriate. If 2.4M Ω is chosen for R2 (I_{REF} = 0.5µA), the equation for R1 and V_{HB} can be approximated as:

$$R1 (k\Omega) = V_{HB} (mV)$$

When hysteresis is obtained in this manner for the MAX982/MAX9_3, the same hysteresis applies to both comparators.

Hysteresis (MAX972/MAX9 4)

Hysteresis can be implemented with any comparator using positive feedback, as shown in Figure 4. This approach generally draws more current than circuits using the HYST pin on the MAX9_1/MAX982/MAX9_3, and the high feedback impedance slows hysteresis. In addition, because the output does not source current, any increase in the upper threshold is dependent on the load or pullup resistor on the output.

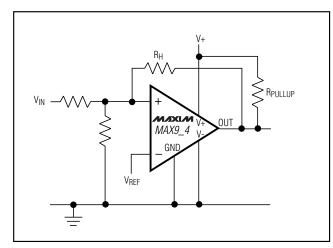


Figure 4. External Hysteresis

Board Layout and Bypassing

Power-supply bypass capacitors are not needed if the supply impedance is low, but 100nF bypass capacitors should be used when the supply impedance is high or when the supply leads are long. Minimize signal lead lengths to reduce stray capacitance between the input and output that might cause instability. Do not bypass the reference output.

Window Detector

The MAX9_3 is ideal for making window detectors (undervoltage/overvoltage detectors). The schematic is shown in Figure 5, with component values selected for a 4.5V undervoltage threshold and a 5.5V overvoltage threshold. Choose different thresholds by changing the values of R1, R2, and R3. To prevent chatter at the output when the supply voltage is close to a threshold, hysteresis has been added using R4 and R5. Taken alone, OUTA would provide an active-low undervoltage indication, and OUTB would give an active-low overvoltage indication. Wired-ORing the two outputs provides an active-high, power-good signal.

The design procedure is as follows:

 Choose the required hysteresis level and calculate values for R4 and R5 according to the formulas in the *Hysteresis* (MAX9_1/MAX982/MAX9_3) section. In this example, ±5mV of hysteresis has been added at the comparator input (V_H = V_{HB}/2). This means that the hysteresis apparent at V_{IN} will be larger because of the input resistor divider.

- 2) Select R1. The leakage current into INB- is normally under 1nA, so the current through R1 should exceed 100nA for the thresholds to be accurate. R1 values up to about $10M\Omega$ can be used, but values in the $100k\Omega$ to $1M\Omega$ range are usually easier to deal with. In this example, choose R1 = $294k\Omega$.
- 3) Calculate R2 + R3. The overvoltage threshold should be 5.5V when V_{IN} is rising. The design equation is as follows:

R2 + R3 = R1 ×
$$\left(\frac{V_{OTH}}{V_{REF} + V_{H}} - 1\right)$$

= 294k Ω × $\left(\frac{5.5}{(1.182 + 0.005)} - 1\right)$
= 1.068M Ω

 Calculate R2. The undervoltage threshold should be 4.5V when V_{IN} is falling. The design equation is as follows:

R2 = (R1 + R2 + R3) ×
$$\frac{(V_{REF} - V_{H})}{V_{UTH}}$$
 - R1
= (294k Ω + 1.068M Ω) × $\frac{(1.182 - 0.005)}{4.5}$
- 294k Ω
= 62.2k Ω

Choose R2 = $61.9k\Omega$ (1% standard value).

5) Calculate R3:

R3 =
$$(R2 + R3) - R2$$

= $1.068M\Omega - 61.9k\Omega$
= $1.006M\Omega$

Choose R3 = $1M\Omega$ (1% standard value)

6) Verify the resistor values. The equations are as follows, evaluated for the above example:

Overvoltage Threshold:

$$V_{OTH} = (V_{REF} + V_{H}) \times \frac{(R1 + R2 + R3)}{R1}$$

= 5.474V

Undervoltage Threshold:

$$V_{UTH} = (V_{REF} - V_{H}) \times \frac{(R1 + R2 + R3)}{(R1 + R2)}$$

= 4.484V

where the hysteresis voltage $V_H = V_{REF} \times \frac{R5}{R4}$

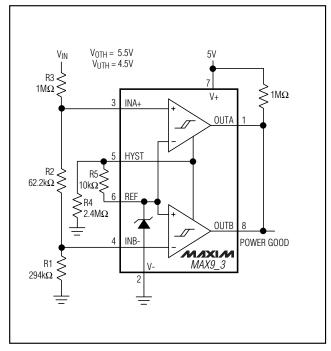


Figure 5. Window Detector

Battery Switchover Circuit

The switchover from line-powered DC to a backup battery is often accomplished with diodes. But this simple method is sometimes unacceptable, due to the voltage drop and associated power loss across the diode in series with the battery. Figure 6's circuit replaces the diode with a P-channel MOSFET controlled by one of the MAX9_3 comparator outputs.

When the DC wall adapter drops below 4V (determined by R1 and R2), OUTA goes low, turning on Q1. Comparator B is used to measure the battery voltage, and gives a "low-battery" indication when the battery drops below 3.6V.

Level-Shifter

Figure 7 shows a circuit to shift from bipolar $\pm 5V$ inputs to single-ended 5V outputs. The $10k\Omega$ resistors protect the comparator inputs, and do not materially affect the circuit's operation.

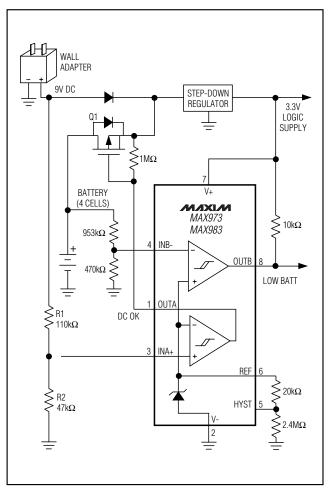


Figure 6. Battery Switchover Circuit

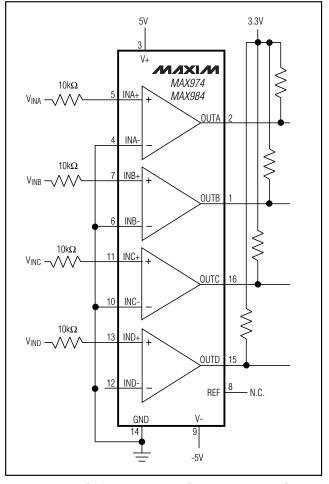
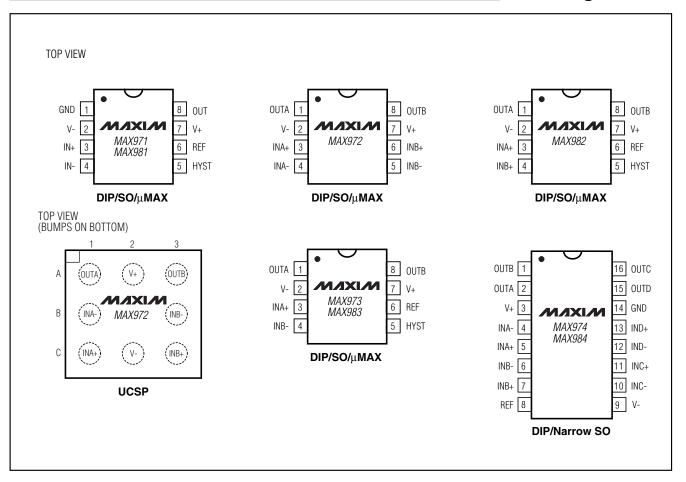


Figure 7. Level Shifter: ±5V Input to Single-Ended 3.3V Output

UCSP Applications Information

For the latest application details on UCSP contruction, dimensions, tape carrier information, printed circuit board techniques, bump-pad layout and recommended reflow temperature profile as well as the latest information on reliability testing results, go to Maxim's web site at www.maxim-ic.com/ucsp to find the Application Note: UCSP-A Wafer-Level Chip-Scale Package.

Pin Configurations



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Ordering Information (continued)

PART	TEMP RANGE	PIN-PACKAGE
MAX971EPA	-40°C to +85°C	8 Plastic Dip
MAX971ESA	-40°C to +85°C	8 SO
MAX972CPA	0°C to +70°C	8 Plastic Dip
MAX972CSA	0°C to +70°C	8 SO
MAX972CUA	0°C to +70°C	8 µMAX
MAX972EBL-T*	-40°C to +85°C	8 UCSP-8
MAX972EPA	-40°C to +85°C	8 Plastic Dip
MAX972ESA	-40°C to +85°C	8 SO
MAX973CPA	0°C to +70°C	8 Plastic Dip
MAX973CSA	0°C to +70°C	8 SO
MAX973CUA	0°C to +70°C	8 µMAX
MAX973EPA	-40°C to +85°C	8 Plastic Dip
MAX973ESA	-40°C to +85°C	8 SO
MAX974CPE	0°C to +70°C	16 Plastic Dip
MAX974CSE	0°C to +70°C	16 Narrow SO
MAX974EPE	-40°C to +85°C	16 Plastic Dip
MAX974ESE	-40°C to +85°C	16 Narrow SO
MAX981CPA	0°C to +70°C	8 Plastic Dip

^{*}UCSP top mark is "ABC."

DADT	TEMP DANCE	DIN DAOKAOE
PART	TEMP RANGE	PIN-PACKAGE
MAX981CSA	0°C to +70°C	8 SO
MAX981CUA	0°C to +70°C	8 μMAX
MAX981EPA	-40°C to +85°C	8 Plastic Dip
MAX981ESA	-40°C to +85°C	8 SO
MAX982CPA	0°C to +70°C	8 Plastic Dip
MAX982CSA	0°C to +70°C	8 SO
MAX982CUA	0°C to +70°C	8 µMAX
MAX982EPA	-40°C to +85°C	8 Plastic Dip
MAX982ESA	-40°C to +85°C	8 SO
MAX983CPA	0°C to +70°C	8 Plastic Dip
MAX983CSA	0°C to +70°C	8 SO
MAX983CUA	0°C to +70°C	8 μMAX
MAX983EPA	-40°C to +85°C	8 Plastic Dip
MAX983ESA	-40°C to +85°C	8 SO
MAX984CPE	0°C to +70°C	16 Plastic Dip
MAX984CSE	0°C to +70°C	16 Narrow SO
MAX984EPE	-40°C to +85°C	16 Plastic Dip
MAX984ESE	-40°C to +85°C	16 Narrow SO

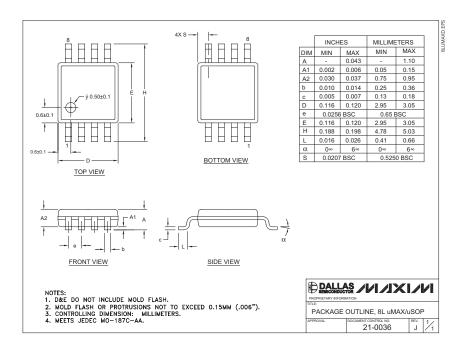
Chip Information

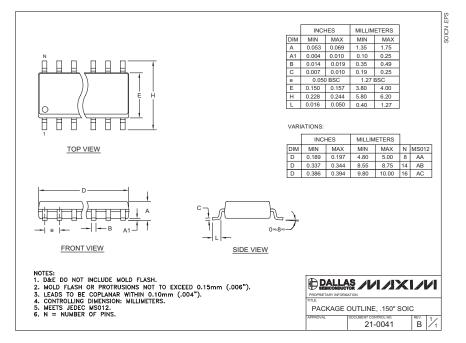
MAX971/MAX972/MAX973/MAX981/MAX982/MAX984 TRANSISTOR COUNT: 164

MAX974/MAX984 TRANSISTOR COUNT: 267

Package Information

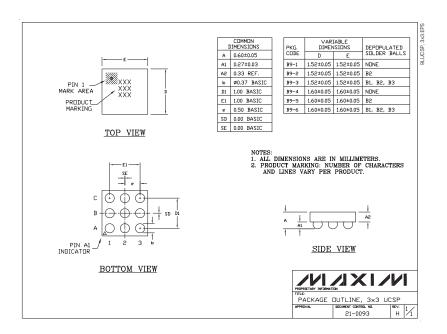
(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)

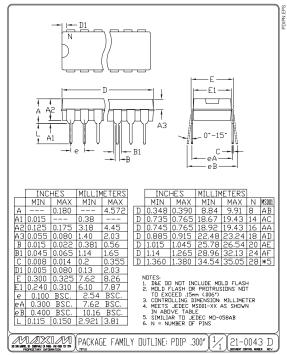




Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)





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